NSN 5962-01-458-7768

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View Online at https://aerobasegroup.com/nsn/5962-01-458-7768 **Body Length:** 1.700 inches **Body Width:** Between 0.350 inches and 0.405 inches **Body Height:** 0.172 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and electrostatic sensitive and low power and burn in, mil-std-883, class b **Inclosure Material:** Silicon **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Terminal Surface Treatment:** Solder **Product Name:** Microcuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power Voltage Rating And Type Per Characteristic: -0.5 volts input and 7.0 volts input **Time Rating Per Chacteristic:** 45.00 nanoseconds af output megawatts **Memory Device Type:** Ram **Special Features:** Circuit function-dual ce **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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